is such that (i) the surface band gap levels are [illegible]

[illegible]

atomic sites charge-compensate each other. In the [illegible]

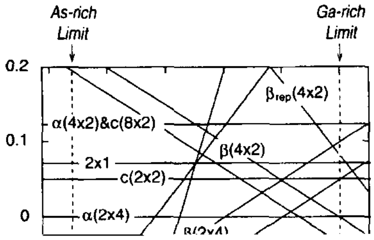
[illegible]

where each term is a difference with respect to σ_0. [illegible]

[illegible]

chemical potential, μ_{Ga} and μ_{As}, and not a function [illegible]

[illegible]



and identical motifs frequencies $\{\omega_M\}$ (i.e., chemically identical). As a consequence, in constructing the AI + AII grooves and the double A steps from the $\beta 2(2\times 4)$ surface, we do not need to transfer any atom between the surfaces and atomic reservoirs. In other words, the formation energies of the AI + AII grooves and the double A steps from the parent dimer are indistinguishable, thus each contributes